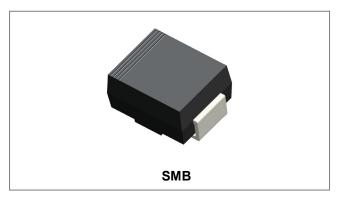






## **SK520B SCHOTTKY RECTIFIER**



### **Features**

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- High Current Capability
- Low Power Loss, High Efficiency
- High Surge Current Capability
- For Use in Low Voltage, High Frequency Inverters,
   Free Wheeling, and Polarity Protection Applications
- This is a Pb Free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### **Circuit Diagram**



### **Applications**

- Switching power supply
- Converters
- · Free-Wheeling diodes
- Reverse battery protection

### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	200	V
Average Rectified Forward Current	lf (AV)	50% duty cycle @T <sub>A</sub> =105°C, rectangular wave form (Note 1)	5	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3ms, Half Sine pulse, T <sub>C</sub> = 25 °C	120	Α

## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V <sub>F1</sub>	@ 5A, Pulse, T <sub>J</sub> = 25 °C	0.85	1.10	V
	V <sub>F2</sub>	@ 5A, Pulse, T <sub>J</sub> = 125 °C	0.74	0.90	V
Reverse Current*	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 25 °C	0.0002	1	mA
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 125 °C	0.05	7	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 \text{ °C}, f_{SIG} = 1MHz$	140	200	pF
Series Inductance	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case.

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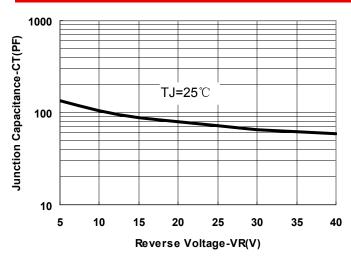




### **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Ambient	$R_{ heta JA}$	DC operation	10	°C/W
Approximate Weight	wt	-	0.09	g

# **Ratings and Characteristics Curves**



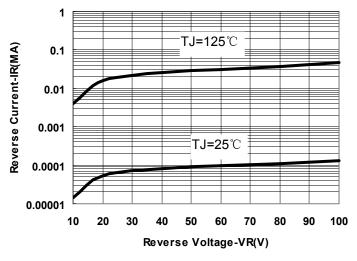


Fig.1-Typical Junction Capacitance

**Fig.2-Typical Values Of Reverse Current** 

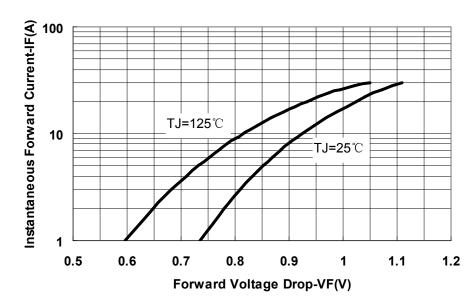


Fig.3-Typical Forward Voltage Drop Characteristics

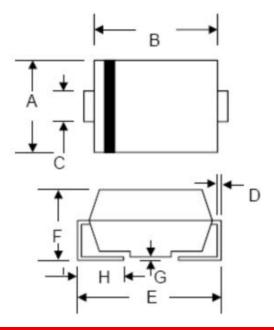
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### **Mechanical Dimensions SMB**



CVMDOL	Millimeters		Inches		
SYMBOL	Min.	Max.	Min.	Max.	
А	3.30	3.94	0.130	0.155	
В	4.06	4.70	0.160	0.185	
С	1.80	2.20	0.071	0.087	
D	0.152	0.305	0.006	0.012	
Е	4.80	5.59	0.189	0.220	
F	2.10	2.60	0.083	0.102	
G	0.051	0.203	0.002	0.008	
Н	0.76	1.52	0.030	0.060	

## Ordering Information

Device	Package	Shipping	
SK520B	SMB (Pb-Free)	3000pcs / reel	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

## **Marking Diagram**

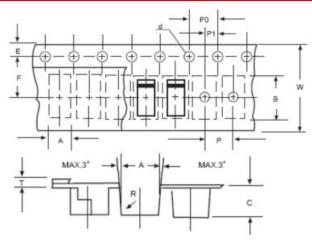
B520 XXXXX Where XXXXX is YYWWL

B = Package type 5 = Forward Current (5A) 20 = Reverse Voltage (200V)

YY = Year WW = Week L = Lot Number

Cautions: Molding resin

# **Carrier Tape Specification SMB**



SYMBOL	Millimeters		
	Min.	Max.	
Α	2.97	3.17	
В	5.70	5.90	
С	2.32	2.52	
d	1.40	1.60	
Е	1.40	1.60	
F	5.60	5.70	
Р	3.90	4.10	
P0	3.90	4.10	
P1	1.90	2.10	
Т	0.25	0.35	
W	11.80	12.20	

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SBAT54CWT1G SBM30-03-TR-E SK310-T SK33A-TP SK34B-TP SS3003CH-TL-E PDS3100Q-7 GA01SHT18 CRS10I30A(TE85L,QM MA4E2501L-1290 MBRB30H30CT-1G BAS 70-02L E6327 DMJ3940-000 SB007-03C-TB-E SB10015M-TL-E SB1003M3-TL-E SK32A-TP SK33B-TP SK35A-TP SK38B-TP NTE505 NTSB30U100CT-1G VS-6CWQ10FNHM3 CRG04(T5L,TEMQ)
ACDBA1100LR-HF ACDBA1200-HF ACDBA140-HF ACDBA2100-HF ACDBA240-HF ACDBA3100-HF CDBQC0530L-HF BAT54-13-F ACDBA340-HF ACDBA260LR-HF